NSN 5961-01-088-8345

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-088-8345 **Inclosure Material:** Plastic **Overall Length:** Between 0.175 inches and 0.185 inches **Terminal Length:** 0.500 inches **Overall Diameter:** Between 0.170 inches and 0.190 inches **Mounting Method: Terminal Terminal Circle Diameter:** 0.100 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 4.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 10.00 microamperes forward current, average peak **Power Rating Per Characteristic:** 280.0 milliwatts small-signal input power, common-collector absolute **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius junction **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure:** Demilitarization: No Fiig: A110a0